

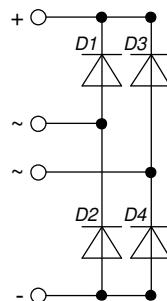
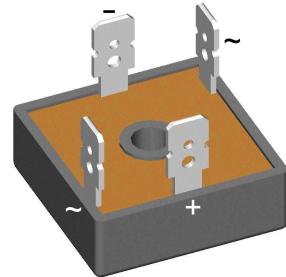
Standard Rectifier Module

1~ Rectifier
$V_{RRM} = 1600 \text{ V}$
$I_{DAV} = 18 \text{ A}$
$I_{FSM} = 550 \text{ A}$

1~ Rectifier Bridge

Part number

VBO36-16NO8



 E72873

Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

Applications:

- Diode for main rectification
- For one phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: FO-B

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- 1/4" fast-on terminals
- Easy to mount with one screw

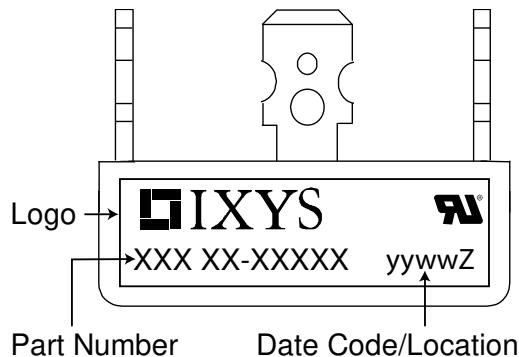
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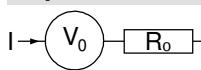
Rectifier

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			1700	V
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			1600	V
I_R	reverse current	$V_R = 1600 \text{ V}$ $V_R = 1600 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		40 1.5	μA mA
V_F	forward voltage drop	$I_F = 15 \text{ A}$ $I_F = 30 \text{ A}$ $I_F = 15 \text{ A}$ $I_F = 30 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		1.04 1.14 0.93 1.06	V V V V
I_{DAV}	bridge output current	$T_C = 85^\circ\text{C}$ rectangular $d = 0.5$	$T_{VJ} = 150^\circ\text{C}$		18	A
V_{F0} r_F	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 150^\circ\text{C}$		0.76 9.1	V $\text{m}\Omega$
R_{thJC}	thermal resistance junction to case				7	K/W
R_{thCH}	thermal resistance case to heatsink			1		K/W
P_{tot}	total power dissipation		$T_C = 25^\circ\text{C}$		17	W
I_{FSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0 \text{ V}$ $T_{VJ} = 150^\circ\text{C}$ $V_R = 0 \text{ V}$		550 595 470 505	A A A A
I^2t	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0 \text{ V}$ $T_{VJ} = 150^\circ\text{C}$ $V_R = 0 \text{ V}$		1.52 1.48 1.11 1.06	kA ² s kA ² s kA ² s kA ² s
C_J	junction capacitance	$V_R = 400 \text{ V}; f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$	18		pF

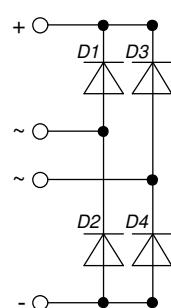
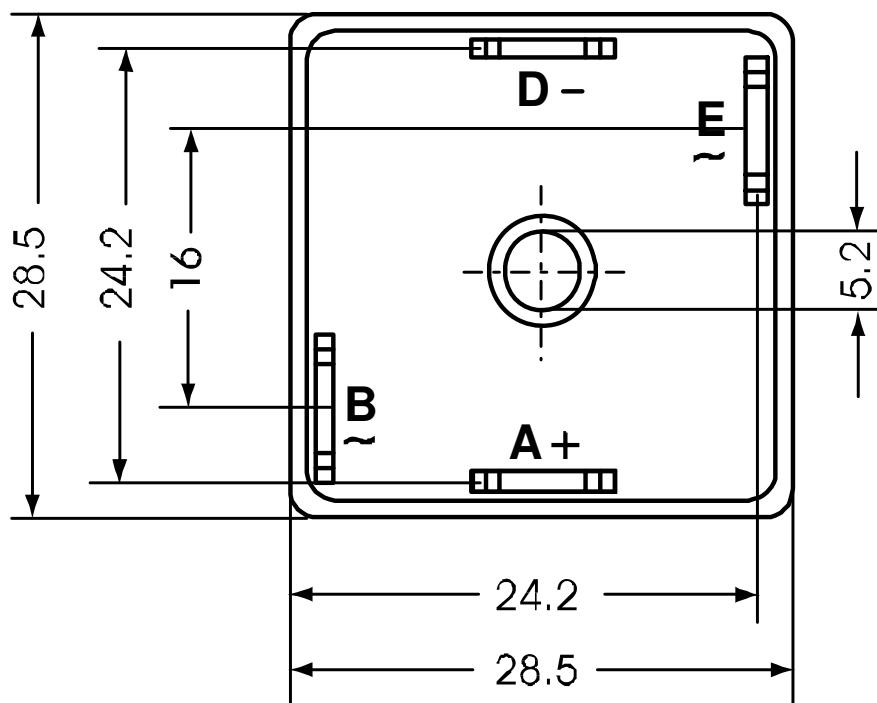
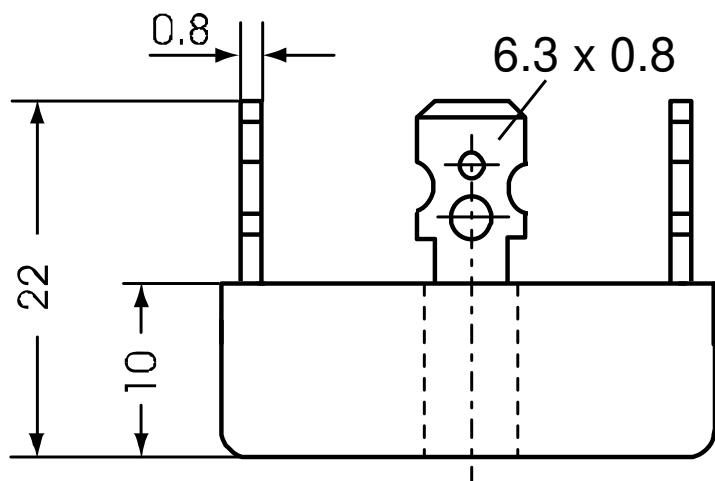
Package FO-B			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			100	A
T_{VJ}	virtual junction temperature		-40		150	°C
T_{op}	operation temperature		-40		125	°C
T_{stg}	storage temperature		-40		125	°C
Weight				19		g
M_D	mounting torque		1.8		2.2	Nm
$d_{Spp/App}$	creepage distance on surface / striking distance through air		terminal to terminal	9.0	7.0	mm
$d_{Spb/Apb}$			terminal to backside	10.0	10.0	mm
V_{ISOL}	isolation voltage	t = 1 second t = 1 minute	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA		3000 2500	V V



Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	VBO36-16NO8	VBO36-16NO8	Box	50	471976

Equivalent Circuits for Simulation
* on die level
 $T_{VJ} = 150^\circ\text{C}$

Rectifier

$V_{0\max}$ threshold voltage 0.76 V
 $R_{0\max}$ slope resistance * 7.9 mΩ

Outlines FO-B


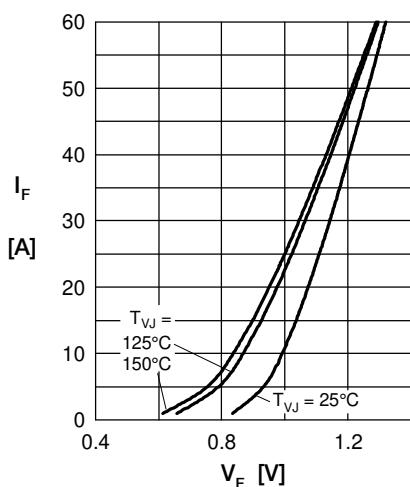
Rectifier


Fig. 1 Forward current vs.
voltage drop per diode

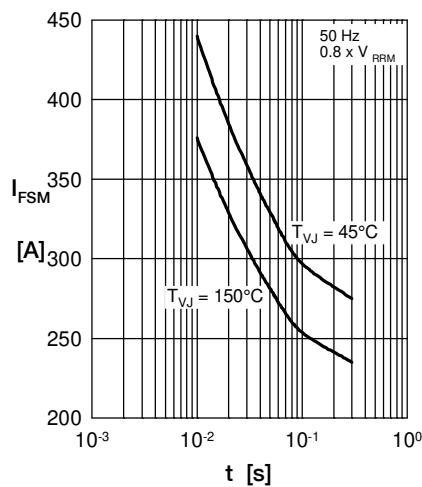


Fig. 2 Surge overload current
vs. time per diode

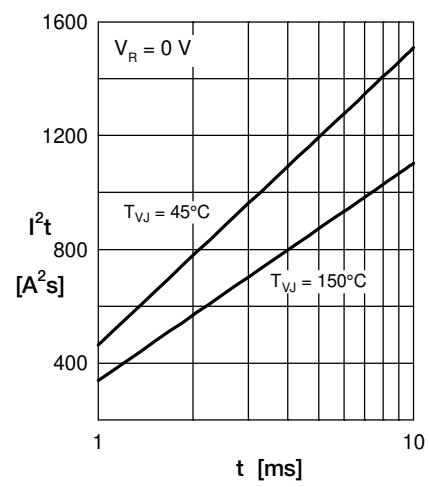


Fig. 3 I^2t vs. time per diode

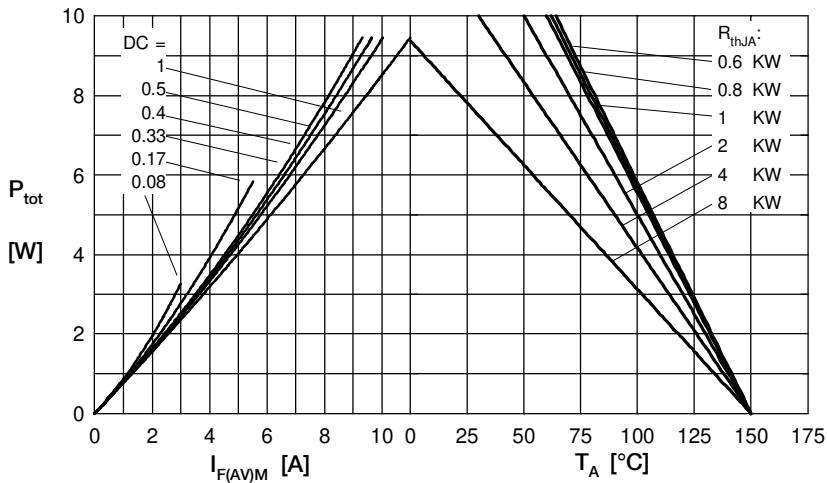


Fig. 4 Power dissipation vs. forward current
and ambient temperature per diode

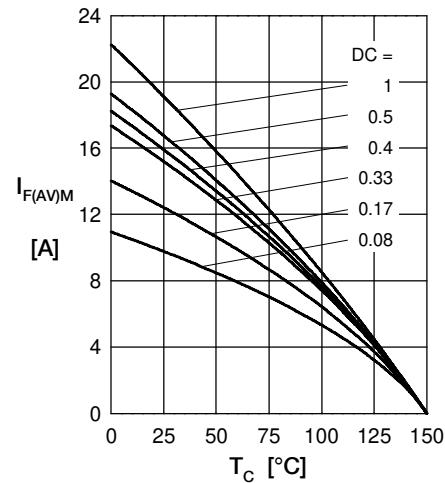


Fig. 5 Max. forward current vs.
case temperature per diode

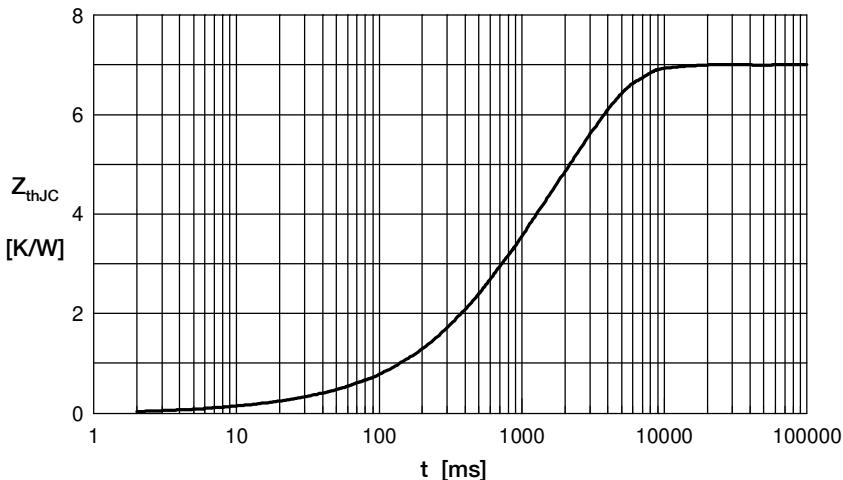


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for Z_{thJC} calculation:

i	R _{th} (K/W)	t _i (s)
1	0.040	0.005
2	0.150	0.030
3	1.710	0.400
4	5.100	2.300

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